2SC4559

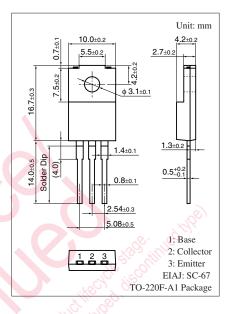
Silicon NPN triple diffusion planar type

For high breakdown voltage high-speed switching

Features

- High-speed switching
- High collector-emitter voltage (Base open) V_{CEO}
- Full-pack package which can be installed to the heat sink with one screw

Parameter				
	Symbol	Rating	Unit	
Collector-base voltage (Emitter open)	V _{CBO}	500	V	
Collector-emitter voltage (E-B short)	V _{CES}	500	V	
Collector-emitter voltage (Base open)	V _{CEO}	400	V	
Emitter-base voltage (Collector open)	V _{EBO}	7	V	
Base current	IB	3	А	
Collector current	I _C	7	Α	
Peak collector current	I _{CP}	15	Α	
Collector power dissipation	P _C	35	W	
$T_a = 25^{\circ}C$		2.0		
Junction temperature	Tj	150	°C	
Storage temperature	T _{stg}	-55 to +150	°C	



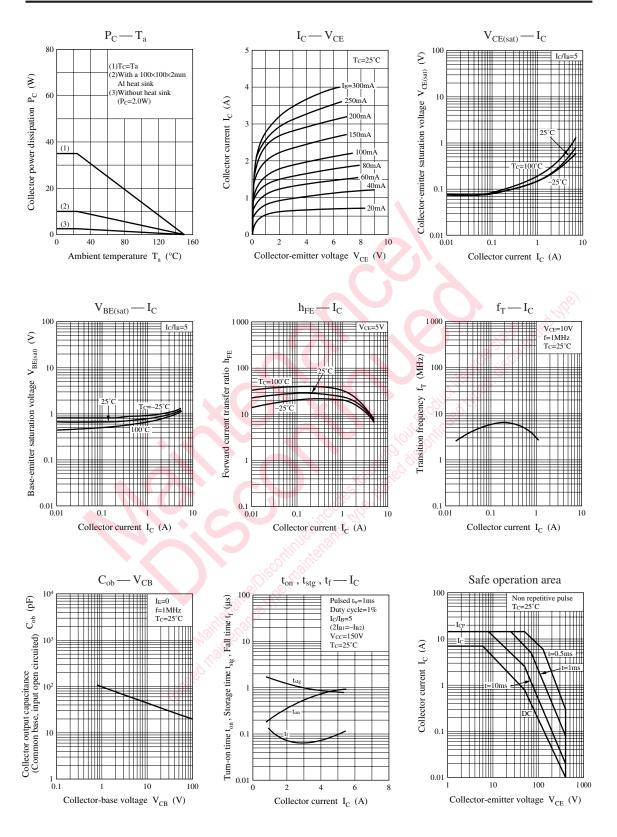
Absolute Maximum Batings $T_c = 25^{\circ}C$

Electrical Characteristics $T_C = 25^{\circ}C \pm 3^{\circ}C$

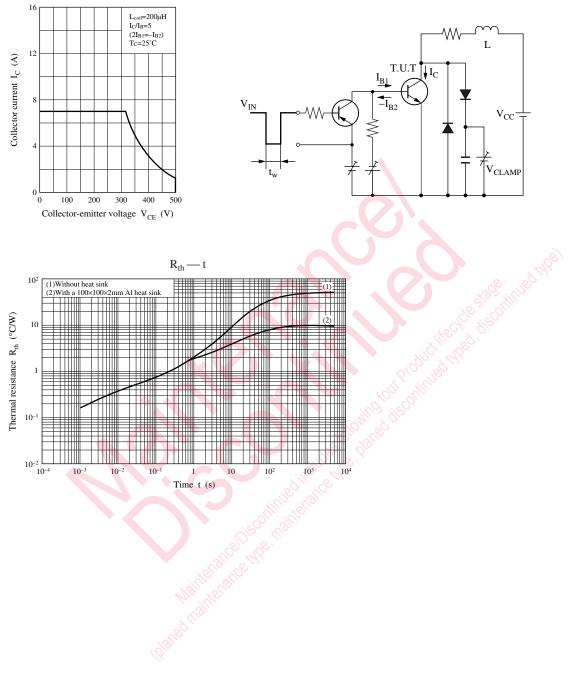
Parameter	Symbol	Conditions	Min	Тур	Max	Unit
Collector-emitter voltage (Base open)	V _{CEO}	$I_{C} = 10 \text{ mA}, I_{B} = 0$	400			V
Collector-base cutoff current (Emitter open)	I _{CBO}	$V_{CB} = 500 \text{ V}, I_E = 0$			100	μΑ
Emitter-base cutoff current (Collector open)	I _{EBO}	$V_{\rm EB} = 5 \text{ V}, I_{\rm C} = 0$			100	μΑ
Forward current transfer ratio	h _{FE1}	$V_{CE} = 5 \text{ V}, I_C = 0.1 \text{ A}$	10			_
- A	h _{FE2}	$V_{CE} = 5 V, I_C = 3 A$	8			
Collector-emitter saturation voltage	V _{CE(sat)}	$I_{C} = 3 A, I_{B} = 0.6 A$			1.0	V
Base-emitter saturation voltage	V _{BE(sat)}	$I_C = 3 A, I_B = 0.6 A$			1.5	V
Transition frequency	$f_{\rm T}$	$V_{CE} = 10 \text{ V}, I_C = 0.5 \text{ A}, f = 1 \text{ MHz}$		10		MHz
Turn-on time	t _{on}	$I_C = 3 A$			1.0	μs
Storage time	t _{stg}	$I_{B1} = 0.6 \text{ A}, I_{B2} = -1.2 \text{ A}$			2.0	μs
Fall time	t _f	$V_{CC} = 150 \text{ V}$			0.3	μs

Note) Measuring methods are based on JAPANESE INDUSTRIAL STANDARD JIS C 7030 measuring methods for transistors.

Panasonic



Safe operation area (Reverse bias)



Safe operation area (Reverse bias) measurement circuit

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